

# 74AUP1G98

Low-power configurable multiple function gate

Rev. 7 — 15 August 2012

Product data sheet

## 1. General description

The 74AUP1G98 provides configurable multiple functions. The output state is determined by eight patterns of 3-bit input. The user can choose the logic functions MUX, AND, OR, NAND, NOR, inverter and buffer. All inputs can be connected to  $V_{CC}$  or GND.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The 74AUP1G98 has Schmitt trigger inputs making it capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage  $V_{T+}$  and the negative voltage  $V_{T-}$  is defined as the input hysteresis voltage  $V_H$ .

## 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
  - ◆ HBM JESD22-A114F exceeds 5000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM JESD22-C101E exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \mu A$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of  $V_{CC}$
- $I_{OFF}$  circuitry provides partial power-down mode operation
- Multiple package options
- Specified from  $-40\text{ }^{\circ}C$  to  $+85\text{ }^{\circ}C$  and  $-40\text{ }^{\circ}C$  to  $+125\text{ }^{\circ}C$



3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AUP1G98GW	−40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363
74AUP1G98GM	−40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886
74AUP1G98GF	−40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm	SOT891
74AUP1G98GN	−40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115
74AUP1G98GS	−40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202

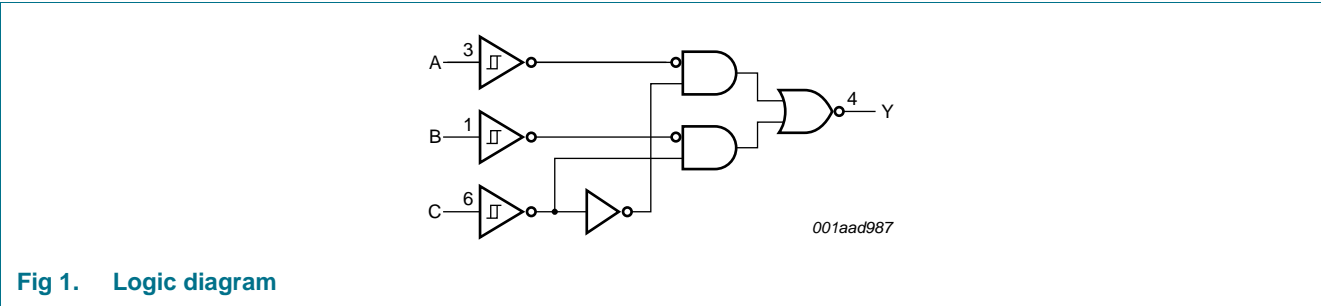
4. Marking

Table 2. Marking

Type number	Marking code <sup>[1]</sup>
74AUP1G98GW	a9
74AUP1G98GM	a9
74AUP1G98GF	a9
74AUP1G98GN	a9
74AUP1G98GS	a9

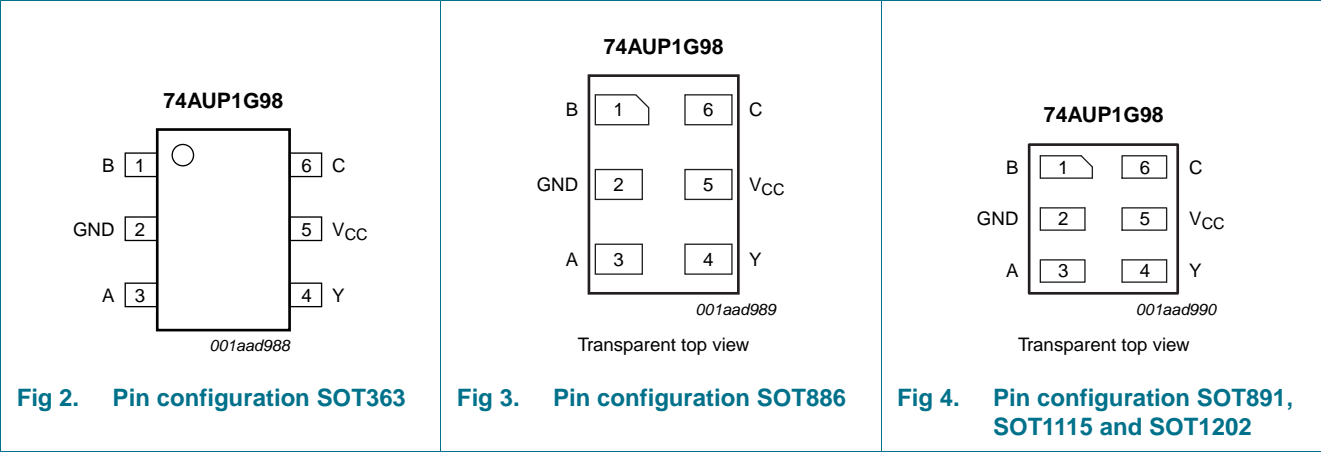
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
B	1	data input
GND	2	ground (0 V)
A	3	data input
Y	4	data output
V <sub>CC</sub>	5	supply voltage
C	6	data input

7. Functional description

Table 4. Function table<sup>[1]</sup>

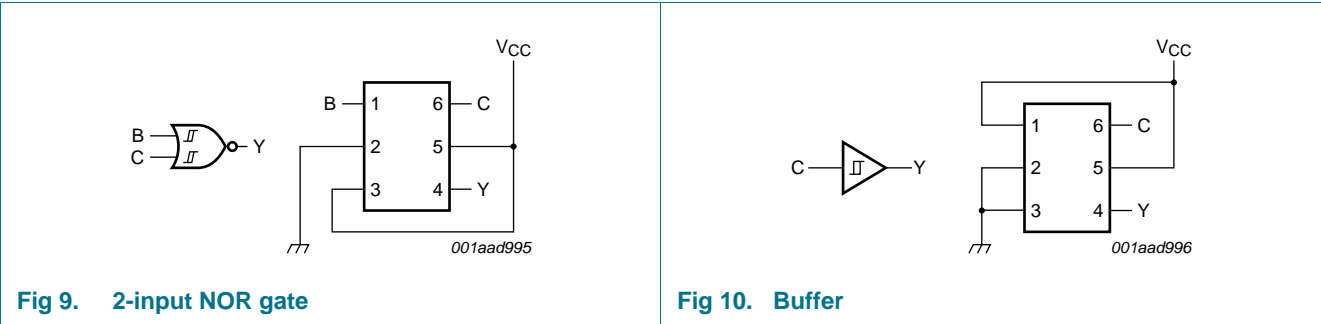
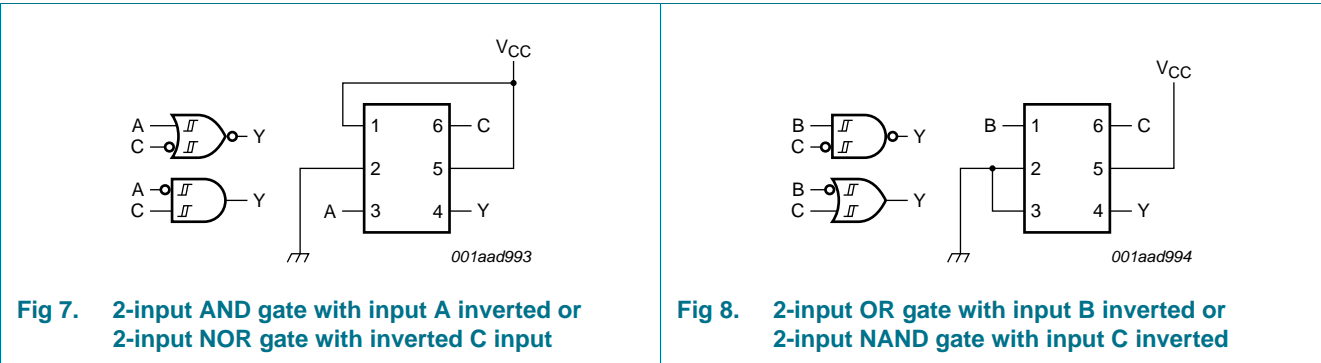
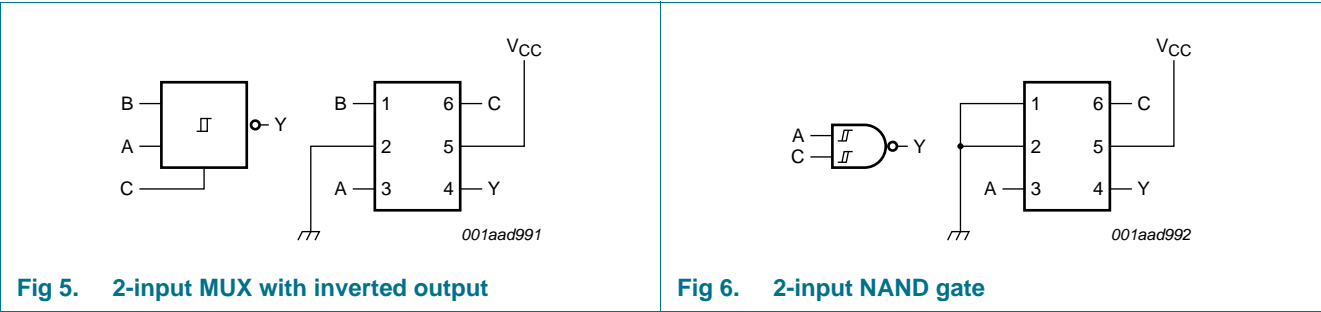
Input			Output
C	B	A	Y
L	L	L	H
L	L	H	H
L	H	L	L
L	H	H	L
H	L	L	H
H	L	H	L
H	H	L	H
H	H	H	L

[1] H = HIGH voltage level;  
L = LOW voltage level.

7.1 Logic configurations

Table 5. Function selection table

Logic function	Figure
2-input MUX with inverted output	see <a href="#">Figure 5</a>
2-input NAND	see <a href="#">Figure 6</a>
2-input NOR with one input inverted	see <a href="#">Figure 7</a>
2-input AND with one input inverted	see <a href="#">Figure 7</a>
2-input NAND with one input inverted	see <a href="#">Figure 8</a>
2-input OR with one input inverted	see <a href="#">Figure 8</a>
2-input NOR	see <a href="#">Figure 9</a>
Buffer	see <a href="#">Figure 10</a>
Inverter	see <a href="#">Figure 11</a>



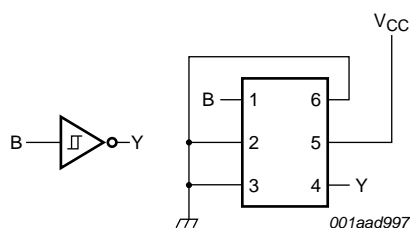


Fig 11. Inverter

## 8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+4.6	V
$I_{IK}$	input clamping current	$V_I < 0$ V	-50	-	mA
$V_I$	input voltage		[1] -0.5	+4.6	V
$I_{OK}$	output clamping current	$V_O < 0$ V	-50	-	mA
$V_O$	output voltage	Active mode and Power-down mode	[1] -0.5	+4.6	V
$I_O$	output current	$V_O = 0$ V to $V_{CC}$	-	$\pm 20$	mA
$I_{CC}$	supply current		-	50	mA
$I_{GND}$	ground current		-50	-	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_{tot}$	total power dissipation	$T_{amb} = -40$ °C to +125 °C	[2] -	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SC-88 packages: above 87.5 °C the value of  $P_{tot}$  derates linearly with 4.0 mW/K.

For XSON6 packages: above 118 °C the value of  $P_{tot}$  derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

Table 7. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		0.8	3.6	V
$V_I$	input voltage		0	3.6	V
$V_O$	output voltage	Active mode	0	$V_{CC}$	V
		Power-down mode; $V_{CC} = 0$ V	0	3.6	V
$T_{amb}$	ambient temperature		-40	+125	°C

## 10. Static characteristics

**Table 8. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.72	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.6	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.1	µA
I <sub>OFF</sub>	power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V	-	-	±0.2	µA
ΔI <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.2	µA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.5	µA
ΔI <sub>CC</sub>	additional supply current	V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 3.3 V	<a href="#">[1]</a> -	-	40	µA
C <sub>I</sub>	input capacitance	V <sub>CC</sub> = 0 V to 3.6 V; V <sub>I</sub> = GND or V <sub>CC</sub>	-	1.1	-	pF
C <sub>O</sub>	output capacitance	V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V	-	1.7	-	pF
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>						
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.55	-	-	V

**Table 8. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.5	µA
I <sub>OFF</sub>	power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V	-	-	±0.5	µA
ΔI <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.6	µA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.9	µA
ΔI <sub>CC</sub>	additional supply current	V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 3.3 V	<a href="#">[1]</a> -	-	50	µA
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>						
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.40	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	µA
I <sub>OFF</sub>	power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V	-	-	±0.75	µA

**Table 8. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$\Delta I_{OFF}$	additional power-off leakage current	$V_I$ or $V_O = 0\text{ V}$ to $3.6\text{ V}$ ; $V_{CC} = 0\text{ V}$ to $0.2\text{ V}$	-	-	$\pm 0.75$	$\mu\text{A}$
$I_{CC}$	supply current	$V_I = \text{GND}$ or $V_{CC}$ ; $I_O = 0\text{ A}$ ; $V_{CC} = 0.8\text{ V}$ to $3.6\text{ V}$	-	-	1.4	$\mu\text{A}$
$\Delta I_{CC}$	additional supply current	$V_I = V_{CC} - 0.6\text{ V}$ ; $I_O = 0\text{ A}$ ; $V_{CC} = 3.3\text{ V}$	[1] -	-	75	$\mu\text{A}$

[1] One input at  $V_{CC} - 0.6\text{ V}$ , other input at  $V_{CC}$  or GND.

## 11. Dynamic characteristics

**Table 9. Dynamic characteristics**Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 13](#).

Symbol	Parameter	Conditions	$T_{amb} = 25\text{ }^{\circ}\text{C}$			$T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$			Unit
			Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	

 **$C_L = 5\text{ pF}$** 

$t_{pd}$	propagation delay	A, B, C to Y; see <a href="#">Figure 12</a>	[2]						
		$V_{CC} = 0.8\text{ V}$	-	23.3	-	-	-	-	ns
		$V_{CC} = 1.1\text{ V}$ to $1.3\text{ V}$	2.9	6.7	12.9	2.7	13.2	13.4	ns
		$V_{CC} = 1.4\text{ V}$ to $1.6\text{ V}$	2.4	4.8	7.7	2.4	8.3	8.7	ns
		$V_{CC} = 1.65\text{ V}$ to $1.95\text{ V}$	2.2	4.0	6.3	1.9	7.0	7.4	ns
		$V_{CC} = 2.3\text{ V}$ to $2.7\text{ V}$	2.0	3.2	4.6	1.8	5.2	5.4	ns
		$V_{CC} = 3.0\text{ V}$ to $3.6\text{ V}$	1.9	2.9	4.0	1.6	4.2	4.4	ns

 **$C_L = 10\text{ pF}$** 

$t_{pd}$	propagation delay	A, B, C to Y; see <a href="#">Figure 12</a>	[2]						
		$V_{CC} = 0.8\text{ V}$	-	27.1	-	-	-	-	ns
		$V_{CC} = 1.1\text{ V}$ to $1.3\text{ V}$	3.3	7.6	14.5	3.0	15.1	15.3	ns
		$V_{CC} = 1.4\text{ V}$ to $1.6\text{ V}$	2.7	5.4	8.8	2.8	9.5	9.9	ns
		$V_{CC} = 1.65\text{ V}$ to $1.95\text{ V}$	2.5	4.6	7.2	2.3	8.0	8.4	ns
		$V_{CC} = 2.3\text{ V}$ to $2.7\text{ V}$	2.4	3.8	5.3	2.2	5.9	6.2	ns
		$V_{CC} = 3.0\text{ V}$ to $3.6\text{ V}$	2.3	3.5	4.7	2.0	4.9	5.2	ns

 **$C_L = 15\text{ pF}$** 

$t_{pd}$	propagation delay	A, B, C to Y; see <a href="#">Figure 12</a>	[2]						
		$V_{CC} = 0.8\text{ V}$	-	30.6	-	-	-	-	ns
		$V_{CC} = 1.1\text{ V}$ to $1.3\text{ V}$	3.6	8.4	16.1	3.3	16.9	17.2	ns
		$V_{CC} = 1.4\text{ V}$ to $1.6\text{ V}$	3.0	6.0	9.7	3.1	10.5	11.0	ns
		$V_{CC} = 1.65\text{ V}$ to $1.95\text{ V}$	2.8	5.1	7.9	2.5	8.9	9.3	ns
		$V_{CC} = 2.3\text{ V}$ to $2.7\text{ V}$	2.7	4.2	5.9	2.5	6.6	7.0	ns
		$V_{CC} = 3.0\text{ V}$ to $3.6\text{ V}$	2.5	3.9	5.2	2.2	5.5	5.8	ns



**Table 9. Dynamic characteristics ...continued**

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 13](#).

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C to +125 °C			Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max (85 °C)	Max (125 °C)	
C <sub>L</sub> = 30 pF									
t <sub>pd</sub>	propagation delay	A, B, C to Y; see <a href="#">Figure 12</a>	<a href="#">[2]</a>						
		V <sub>CC</sub> = 0.8 V	-	38.7	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.5	10.7	21.1	4.1	22.0	22.4	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.8	7.6	12.3	3.8	13.5	14.2	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.5	6.3	10.1	3.1	11.3	11.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	3.4	5.3	7.5	3.2	8.4	8.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	3.2	5.0	6.7	2.9	7.1	7.5	ns
C <sub>L</sub> = 5 pF, 10 pF, 15 pF and 30 pF									
C <sub>PD</sub>	power dissipation capacitance	f <sub>i</sub> = 1 MHz; V <sub>I</sub> = GND to V <sub>CC</sub>	<a href="#">[3]</a>						
		V <sub>CC</sub> = 0.8 V	-	2.7	-	-	-	-	pF
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.9	-	-	-	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	3.0	-	-	-	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	3.2	-	-	-	-	pF
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	3.8	-	-	-	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	4.4	-	-	-	-	pF

[1] All typical values are measured at nominal V<sub>CC</sub>.

[2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.

[3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

12. Waveforms

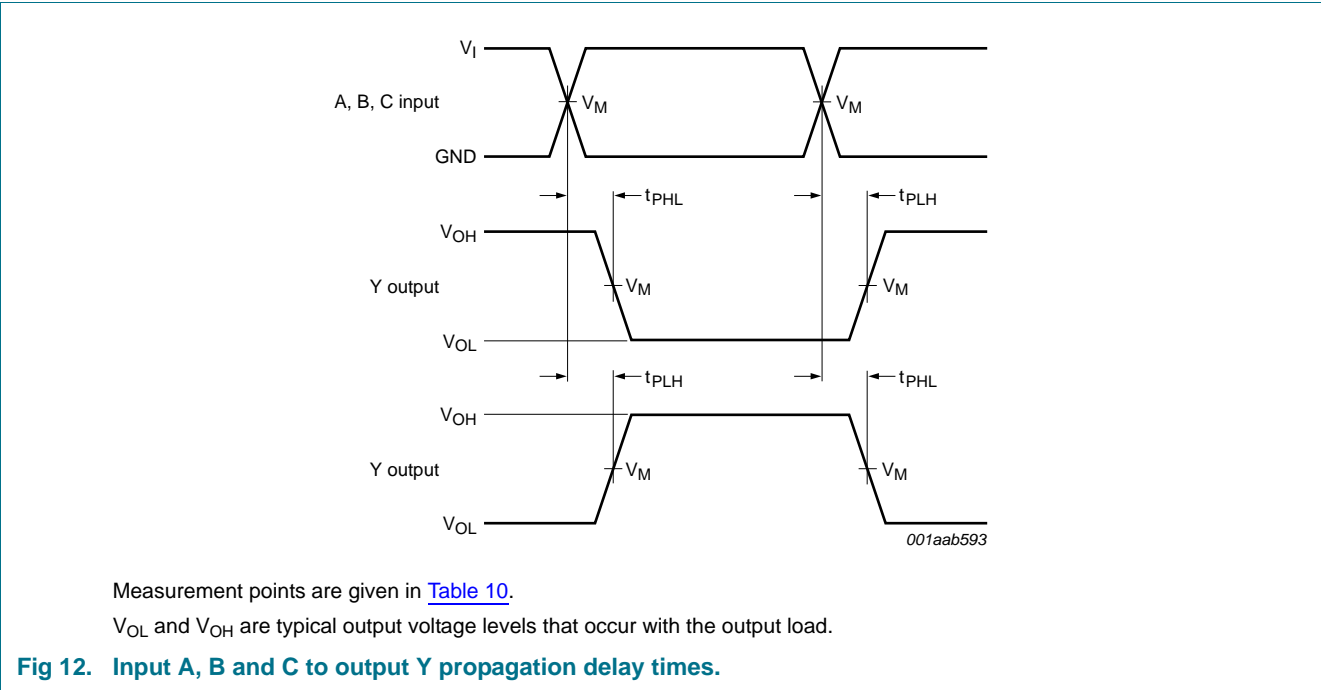
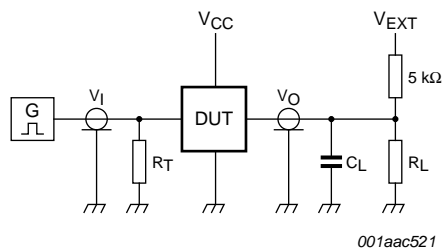


Table 10. Measurement points

Supply voltage	Output	Input		
$V_{CC}$	$V_M$	$V_M$	$V_I$	$t_r = t_f$
0.8 V to 3.6 V	$0.5V_{CC}$	$0.5V_{CC}$	$V_{CC}$	$\leq 3.0$ ns



Test data is given in [Table 11](#).

Definitions for test circuit:

$R_L$  = Load resistance.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

$V_{EXT}$  = External voltage for measuring switching times.

**Fig 13. Test circuit for measuring switching times**

**Table 11. Test data**

Supply voltage	Load		$V_{EXT}$		
$V_{CC}$	$C_L$	$R_L$ [1]	$t_{PLH}$ , $t_{PHL}$	$t_{PZH}$ , $t_{PHZ}$	$t_{PZL}$ , $t_{PLZ}$
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	$2V_{CC}$

[1] For measuring enable and disable times  $R_L = 5\text{ k}\Omega$ , for measuring propagation delays, setup and hold times and pulse width  $R_L = 1\text{ M}\Omega$ .

## 13. Transfer characteristics

**Table 12. Transfer characteristics**

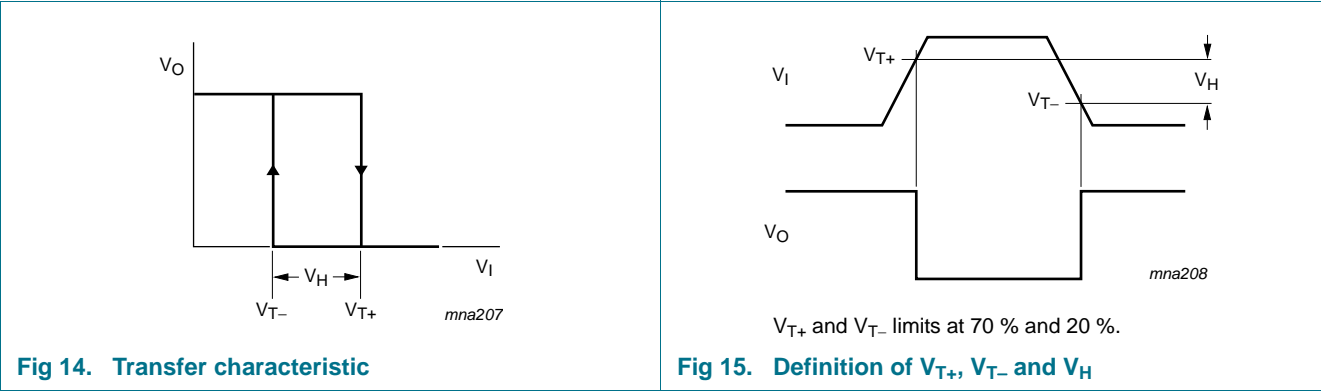
Voltages are referenced to GND (ground = 0 V; for test circuit see [Figure 13](#)).

Symbol	Parameter	Conditions	$T_{amb} = 25\text{ }^{\circ}\text{C}$			$T_{amb} = -40\text{ }^{\circ}\text{C to } +125\text{ }^{\circ}\text{C}$			Unit
			Min	Typ	Max	Min	Max (85 °C)	Max (125 °C)	
$V_{T+}$	positive-going threshold voltage	see <a href="#">Figure 14</a> and <a href="#">Figure 15</a>							
		$V_{CC} = 0.8\text{ V}$	0.30	-	0.60	0.30	0.60	0.62	V
		$V_{CC} = 1.1\text{ V}$	0.53	-	0.90	0.53	0.90	0.92	V
		$V_{CC} = 1.4\text{ V}$	0.74	-	1.11	0.74	1.11	1.13	V
		$V_{CC} = 1.65\text{ V}$	0.91	-	1.29	0.91	1.29	1.31	V
		$V_{CC} = 2.3\text{ V}$	1.37	-	1.77	1.37	1.77	1.80	V
		$V_{CC} = 3.0\text{ V}$	1.88	-	2.29	1.88	2.29	2.32	V
$V_{T-}$	negative-going threshold voltage	see <a href="#">Figure 14</a> and <a href="#">Figure 15</a>							
		$V_{CC} = 0.8\text{ V}$	0.10	-	0.60	0.10	0.60	0.60	V
		$V_{CC} = 1.1\text{ V}$	0.26	-	0.65	0.26	0.65	0.65	V
		$V_{CC} = 1.4\text{ V}$	0.39	-	0.75	0.39	0.75	0.75	V
		$V_{CC} = 1.65\text{ V}$	0.47	-	0.84	0.47	0.84	0.84	V
		$V_{CC} = 2.3\text{ V}$	0.69	-	1.04	0.69	1.04	1.04	V
		$V_{CC} = 3.0\text{ V}$	0.88	-	1.24	0.88	1.24	1.24	V

Table 12. Transfer characteristics ...continued  
Voltages are referenced to GND (ground = 0 V; for test circuit see Figure 13).

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C to +125 °C			Unit
			Min	Typ	Max	Min	Max (85 °C)	Max (125 °C)	
V <sub>H</sub>	hysteresis voltage	(V <sub>T+</sub> - V <sub>T-</sub> ); see Figure 14, Figure 15, Figure 16 and Figure 17							
		V <sub>CC</sub> = 0.8 V	0.07	-	0.50	0.07	0.50	0.50	V
		V <sub>CC</sub> = 1.1 V	0.08	-	0.46	0.08	0.46	0.46	V
		V <sub>CC</sub> = 1.4 V	0.18	-	0.56	0.18	0.56	0.56	V
		V <sub>CC</sub> = 1.65 V	0.27	-	0.66	0.27	0.66	0.66	V
		V <sub>CC</sub> = 2.3 V	0.53	-	0.92	0.53	0.92	0.92	V
		V <sub>CC</sub> = 3.0 V	0.79	-	1.31	0.79	1.31	1.31	V

14. Waveforms transfer characteristics



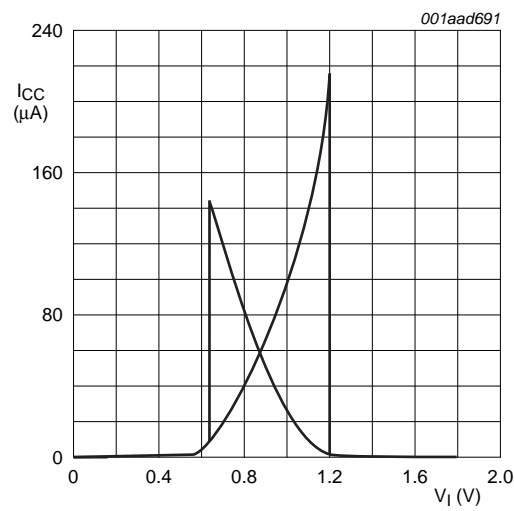


Fig 16. Typical transfer characteristics;  $V_{CC} = 1.8\text{ V}$

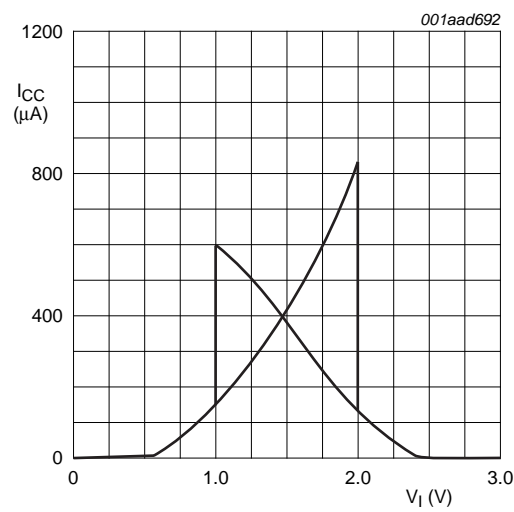


Fig 17. Typical transfer characteristics;  $V_{CC} = 3.0\text{ V}$

15. Package outline

Plastic surface-mounted package; 6 leadsSOT363

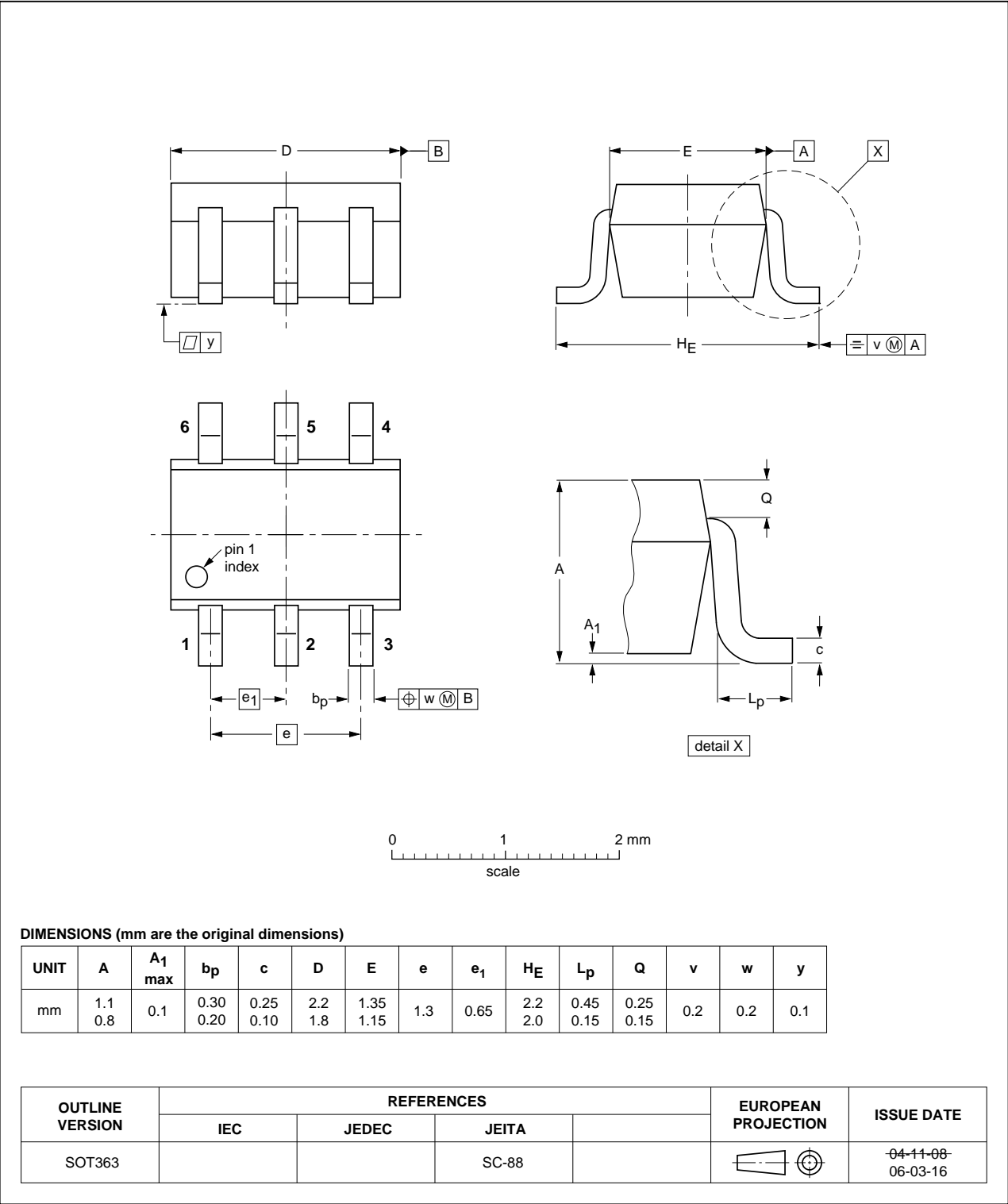


Fig 18. Package outline SOT363 (SC-88)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

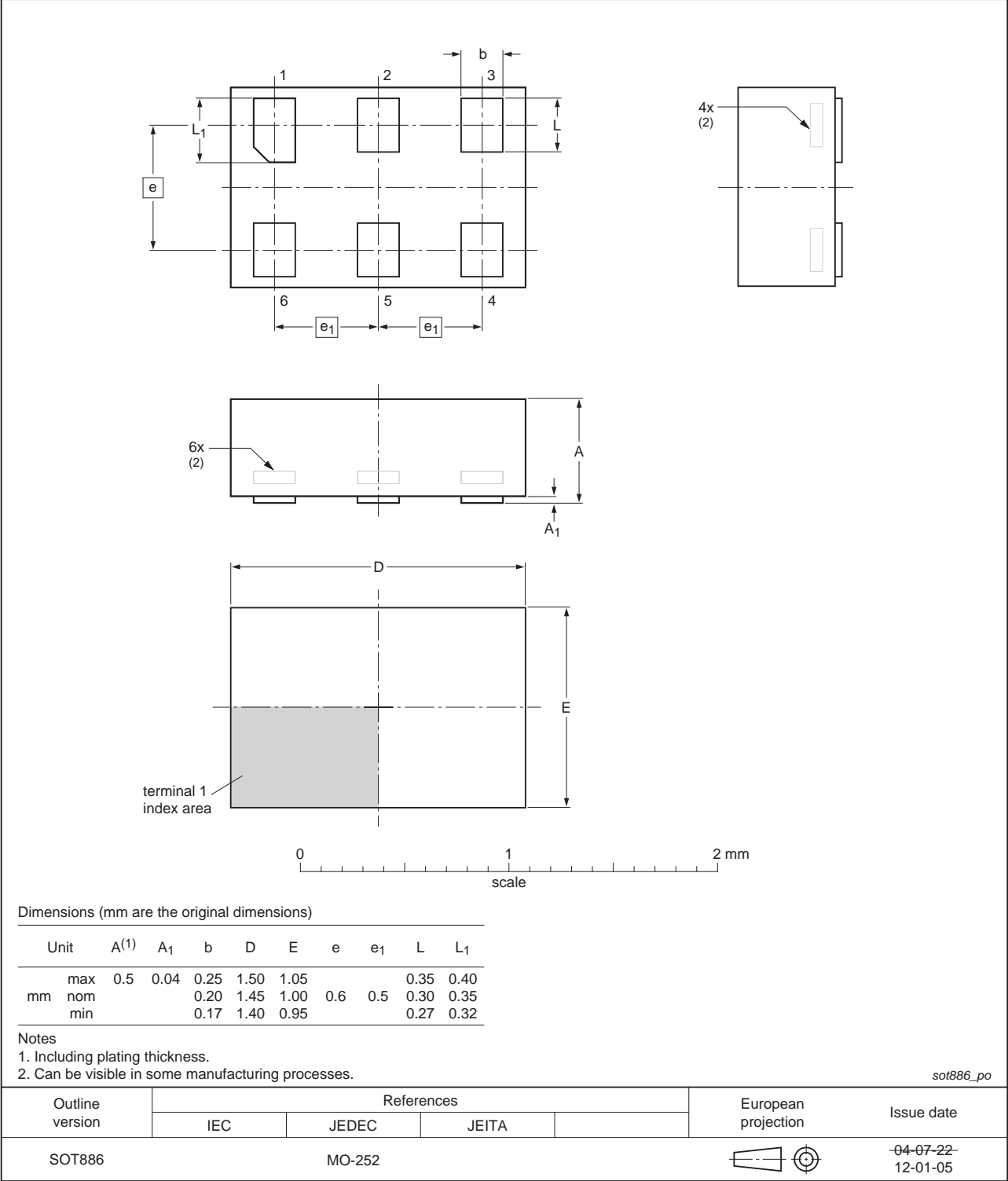


Fig 19. Package outline SOT886 (XSON6)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

SOT891

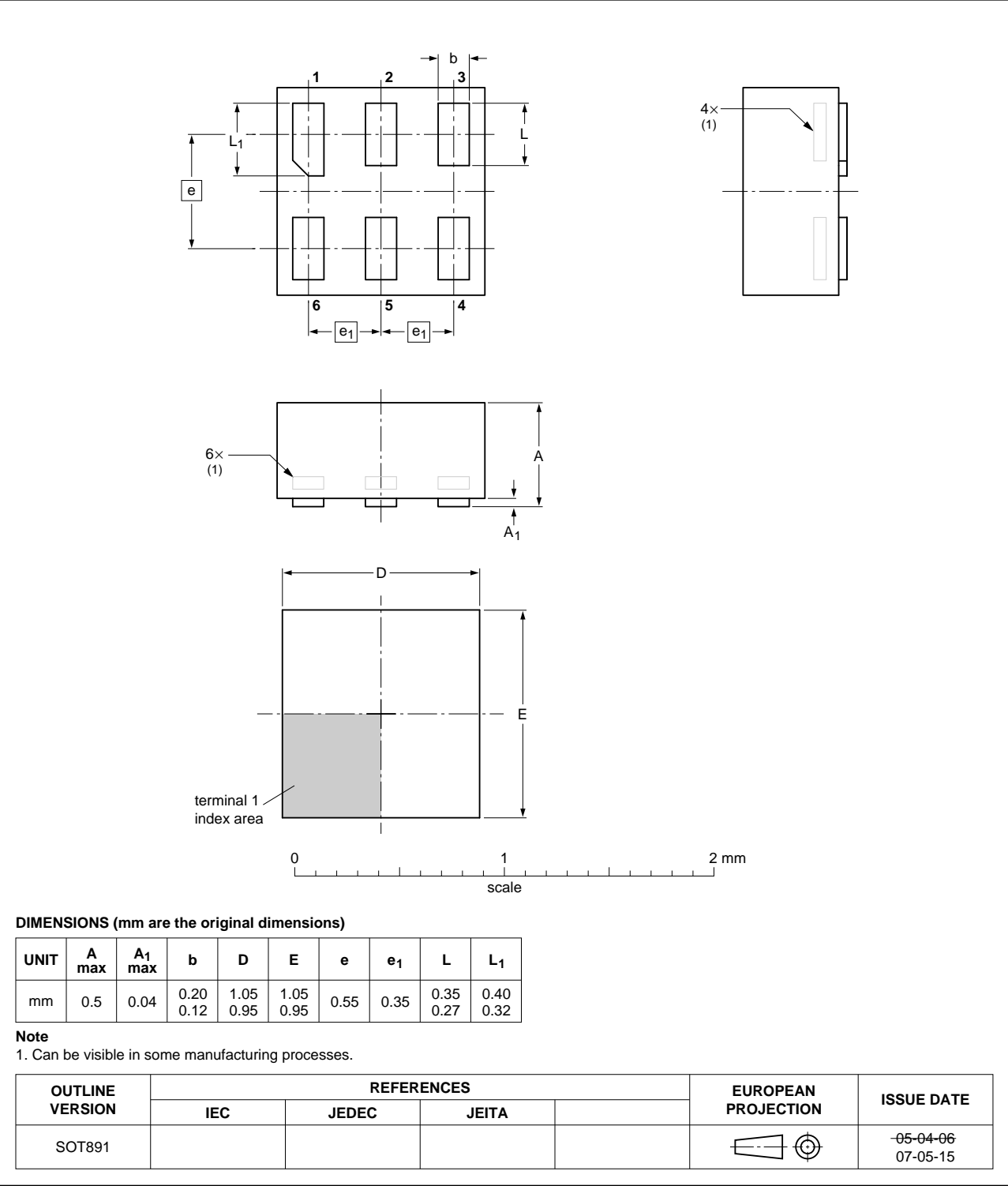
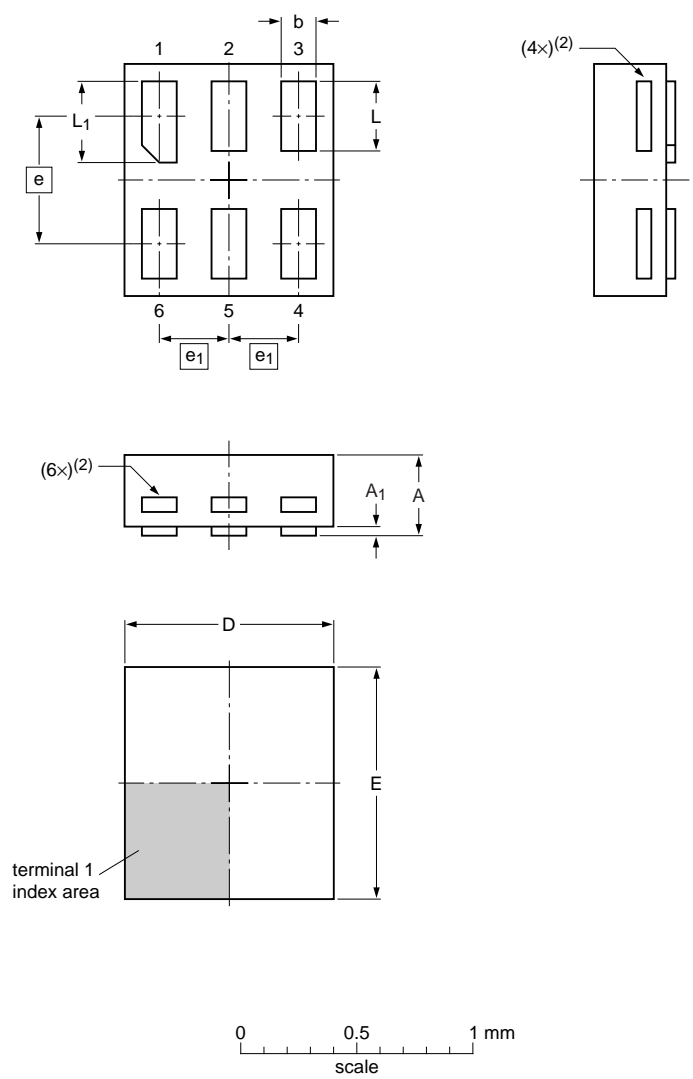


Fig 20. Package outline SOT891 (XSON6)



XSON6: extremely thin small outline package; no leads;  
6 terminals; body 0.9 x 1.0 x 0.35 mm

SOT1115



Dimensions

Unit	A <sup>(1)</sup>	A <sub>1</sub>	b	D	E	e	e <sub>1</sub>	L	L <sub>1</sub>
mm	max	0.35	0.04	0.20	0.95	1.05		0.35	0.40
	nom			0.15	0.90	1.00	0.55	0.30	0.35
	min			0.12	0.85	0.95		0.27	0.32

Note

- 1. Including plating thickness.
- 2. Visible depending upon used manufacturing technology.

sot1115\_po

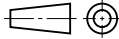
Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1115						<del>10-04-02</del> 10-04-07

Fig 21. Package outline SOT1115 (XSON6)

XSON6: extremely thin small outline package; no leads;  
6 terminals; body 1.0 x 1.0 x 0.35 mm

SOT1202

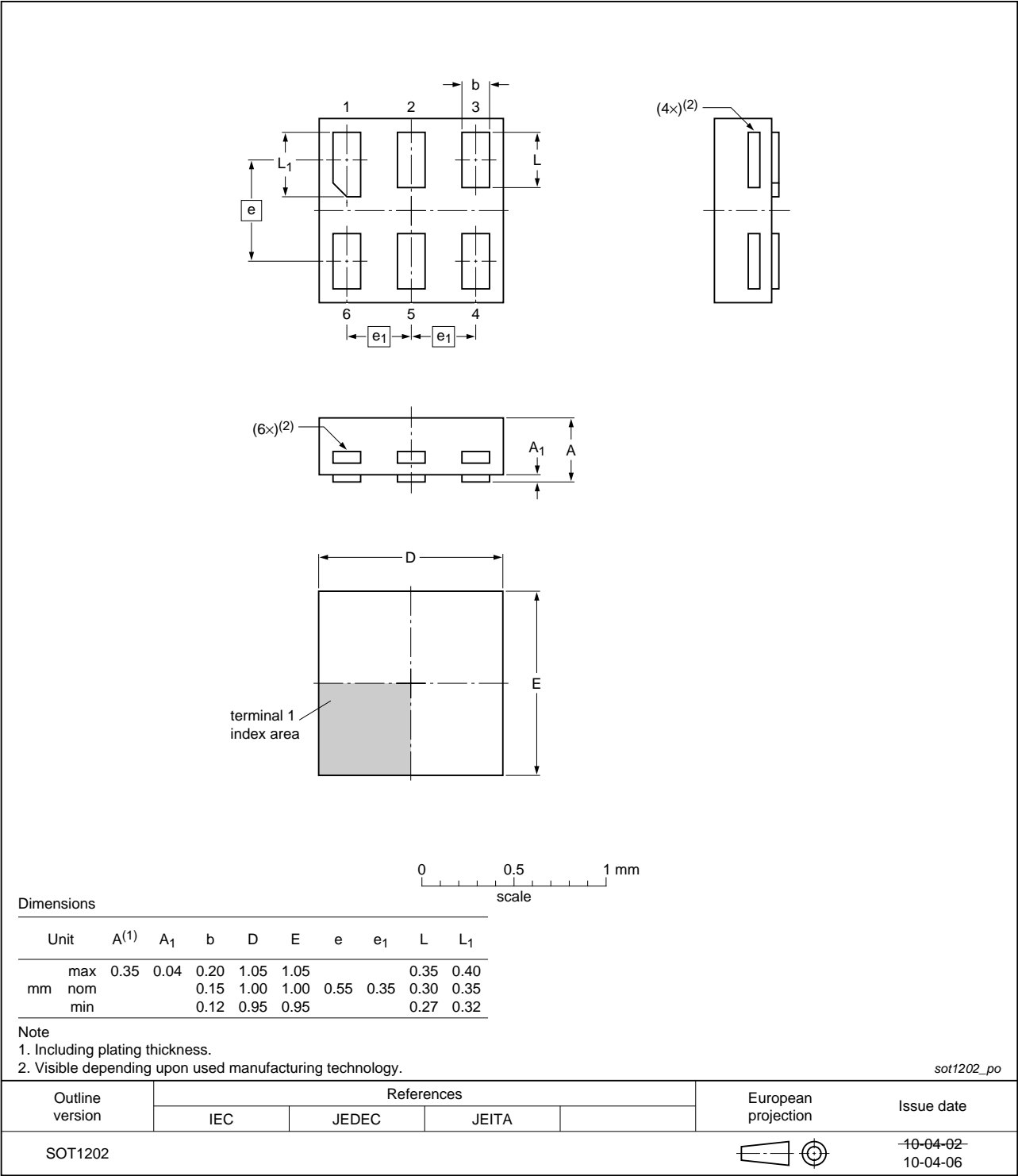


Fig 22. Package outline SOT1202 (XSON6)

## 16. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

## 17. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G98 v.7	20120815	Product data sheet	-	74AUP1G98 v.6
Modifications:	• Package outline drawing of SOT886 ( <a href="#">Figure 19</a> ) modified.			
74AUP1G98 v.6	20111128	Product data sheet	-	74AUP1G98 v.5
74AUP1G98 v.5	20110105	Product data sheet	-	74AUP1G98 v.4
74AUP1G98 v.4	20101012	Product data sheet	-	74AUP1G98 v.3
74AUP1G98 v.3	20090629	Product data sheet	-	74AUP1G98 v.2
74AUP1G98 v.2	20090402	Product data sheet	-	74AUP1G98 v.1
74AUP1G98 v.1	20061108	Product data sheet	-	-

## 18. Legal information

### 18.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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## 20. Contents

1	General description .....	1
2	Features and benefits .....	1
3	Ordering information .....	2
4	Marking .....	2
5	Functional diagram .....	2
6	Pinning information .....	3
6.1	Pinning .....	3
6.2	Pin description .....	3
7	Functional description .....	3
7.1	Logic configurations .....	4
8	Limiting values .....	5
9	Recommended operating conditions .....	5
10	Static characteristics .....	6
11	Dynamic characteristics .....	8
12	Waveforms .....	10
13	Transfer characteristics .....	11
14	Waveforms transfer characteristics .....	12
15	Package outline .....	14
16	Abbreviations .....	19
17	Revision history .....	19
18	Legal information .....	20
18.1	Data sheet status .....	20
18.2	Definitions .....	20
18.3	Disclaimers .....	20
18.4	Trademarks .....	21
19	Contact information .....	21
20	Contents .....	22

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